

Number of Components:	Two	Minimum Bond Line Cure Schedule*:	
Mix Ratio By Weight:	1:1	175°C	1 Minute
Specific Gravity:		150°C	5 Minutes
Part A	1.25	120°C	15 Minutes
Part B	2.03	80°C	90 Minutes
Pot Life:	3 Days		
Shelf Life:	One year at room temperature.		

Note: Container(s) should be kept closed when not in use. For filled systems, mix contents of each container (A & B) thoroughly before mixing the two together. *Please see Applications Note available on our website.

Product Description:

EPO TEK[®] H70S is a modified version of EPO TEK[®] H70E, designed primarily for die stamping. It is a highly reliable, alumina- filled epoxy with a smooth, flowable consistency, designed for chip bonding in micro-electronic and opto-electronic applications.

EPO-TEK[®] H70S Advantages & Application Notes:

- Heat-sinking adhesive. It is particularly recommended for thermal management applications where good heat dissipation is necessary.
- Easy to use. It can be screen printed, machine dispensed, stamped, or hand applied.
- Die attach adhesive designed to be used in the 300°C range to resist TC wire bonding operations. Meets JEDEC Level III and II packaging criteria.
- Excellent adhesion to ferrous and non-ferrous metals, lead-frame die paddle, glass, ceramic, kovar, and PCB.
- Can be cured very rapidly, it is an excellent material to use for making fast circuit repairs. Can be snap-cured for in-line semiconductor die-bonding.
- Suggested for potting applications due to easy flow and pouring – works well with thermistors into cavities.

Typical Properties: (To be used as a guide only, not as a specification. Data below is not guaranteed. Different batches, conditions and applications yield differing results; Cure condition: 150°C/1 hour; * denotes test on lot acceptance basis)

Physical Properties:	
*Color: Part A: Cream Part B: Grey	Weight Loss:
*Consistency: Pourable paste	@ 200°C:
*Viscosity (@ 100 RPM/23°C): 1,300 – 1,800 cPs	@ 250°C: 2.25%
Thixotropic Index: 1.37	@ 300°C:
*Glass Transition Temp.(Tg): ≥ 50°C (Dynamic Cure 20—200°C /ISO 25 Min; Ramp -10—200°C @ 20°C/Min)	Operating Temp:
Coefficient of Thermal Expansion (CTE):	Continuous: - 55°C to 200°C
Below Tg: 40 x 10 ⁻⁶ in/in/°C	Intermittent: - 55°C to 300°C
Above Tg: 190 x 10 ⁻⁶ in/in/°C	Storage Modulus @ 23°C: 350,092 psi
Shore D Hardness: 83	Ions: Cl ⁻ 231 ppm
Lap Shear Strength @ 23°C: > 2,000 psi	Na ⁺ 95 ppm
Die Shear Strength @ 23°C: ≥ 10 Kg / 3,400 psi	NH ₄ ⁺
Degradation Temp. (TGA): 400°C	K ⁺ 39 ppm
	*Particle Size: ≤ 20 Microns
Thermal Properties:	
Thermal Conductivity: 0.44 W/mK	
Electrical Properties:	
Dielectric Constant (1KHz): 4.97	Volume Resistivity: ≥ 7x10 ¹³ Ohm-cm
Dissipation Factor (1KHz): 0.0161	

EPOXY TECHNOLOGY, INC.

14 Fortune Drive, Billerica, MA 01821-3972 Phone: 978.667.3805 Fax: 978.663.9782

www.EPOTEK.com

Epoxy and Adhesives for Demanding Applications™

This information is based on data and tests believed to be accurate. Epoxy Technology, Inc. makes no warranties (expressed or implied) as to its accuracy and assumes no liability in connection with any use of this product.